

Features

- Wide operating voltage range
- Seven-way high-gain Darlington array
- High output voltage (up to 50V)
- High output current (up to 500mA)
- It can be directly connected with TTL, CMOS and PMOS
- Built-in clamp diode for sensitive load

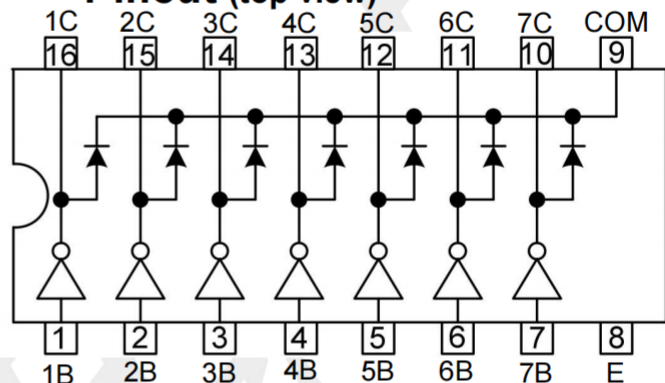
Applications

- Relay drive
- Dc lighting drive
- Stepper motor drive
- Solenoid valve
- Dc brushless motor drive

General Description

The are high-voltage, high-current darlington drivers comprised of seven NPN Darlington pairs. All units feature integral clamp diodes for switching inductive loads. Applications include relay, hammer, lamp and display (LED)drivers.

Pinout (top view)



SOP16

Pin Configurations

Pin Number	Pin Name	Pin Function
1	1B	Input pair1
2	2B	Input pair2
3	3B	Input pair3
4	4B	Input pair4
5	5B	Input pair5
6	6B	Input pair6
7	7B	Input pair7
8	E	Common Emitter (ground)
9	COM	Common Clamp Diodes
10	7C	Output pair7
11	6C	Output pair6
12	5C	Output pair5
13	4C	Output pair4
14	3C	Output pair3
15	2C	Output pair2
16	1C	Output pair1

Marking:



Absolute Maximum Ratings

At 25°C free-air temperature (unless otherwise noted)

Symbol	Parameter	MIN	MAX	UNIT
V _{CC}	Collector to emitter voltage	--	50	V
V _R	Clamp diode reverse voltage(2)	--	50	V
V _I	Input voltage(2)	--	30	V
I _{CP}	Peak collector current	See typical characteristics		mA
I _{OK}	Output clamp current	--	500	mA
I _{TE}	Total emitter-terminal current	--	-2.5	A
T _A	Operating free-air temperature range	-20	+70	°C
θ _{JA}	Thermal Resistance Junction-to-Ambient(3)	--	63	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case(4)	--	12	°C/W
T _J	Operating virtual junction temperature	--	+150	°C
T _{STG}	Storage temperature range	-65	+150	°C
ESD	Human Body Model	--	3000	V

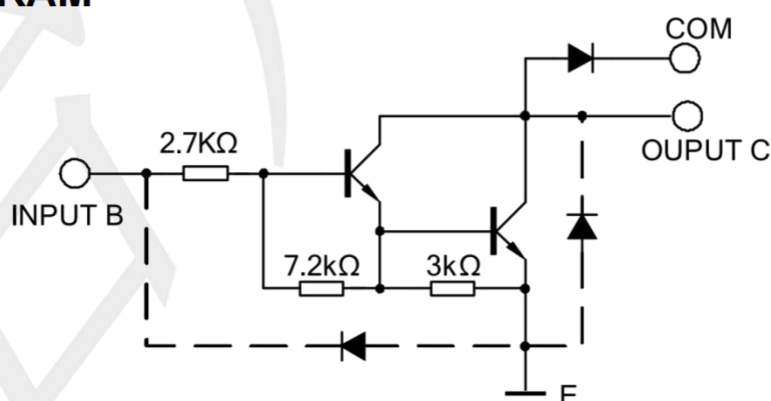
(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

(3) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $PD = (T_J(max) - T_A) / \theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

(4) Maximum power dissipation is a function of T_J(max), θ_{JC}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $PD = (T_J(max) - T_A) / \theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

BLOCK DIAGRAM



Note: The input and output parasitic diodes cannot be used as clamp diodes.

Electrical Characteristics

(TA=+25°C, unless otherwise specified)

SYM BOL	PARAMETER	Test Figure	Test Conditions	MIN	TYP	MAX	UNIT
VCC	Collector to Emitter voltage			--	--	50	V
TA	Operating Ambient Temperature			-40	--	+105	°C
V _I (on)	On-state input voltage	Figure 6	VCE = 2 V, IC = 200 mA	--	--	2.4	V
			VCE = 2 V, IC = 250 mA	--	--	2.7	V
			VCE = 2 V, IC = 300 mA	--	--	3.0	V
V _{CE} (sat)	Collector-emitter saturation voltage	Figure 5	I _I = 250 μA, IC = 100 mA	--	0.9	1.1	V
			I _I = 350 μA, IC = 200 mA	--	1.0	1.3	V
			I _I = 500 μA, IC = 350 mA	--	1.2	1.6	V
I _{CEX}	Collector cutoff current	Figure 1	VCE = 50 V, I _I = 0	--	--	50	uA
		Figure 2	VCE = 50 V, I _I = 0 TA=+150°C	--	--	100	uA
V _F	Clamp forward voltage	Figure 8	IF = 350 mA	--	1.7	2.0	V
I _I (off)	Off-state input current	Figure 3	VCE = 50 V, IC = 500 μA	50	65	--	uA
I _I	Input current	Figure 4	V _I = 3.85V	--	0.93	1.35	mA
			V _I = 5.0V	--	--	--	mA
			V _I = 12V	--	--	--	mA
I _R	Clamp reverse current	Figure 7	VR = 50 V	--	--	50	uA
			VR = 50 V, TA=+70°C	--	--	100	uA
Ci	Input capacitance		VI = 0, f = 1 MHz	--	15	25	PF

Switching Characteristics

(TA = +25°C, unless otherwise specified)

SYMBOL	PARAMETER	Test Conditions	MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	See Figure 9	--	0.25	1.0	μs
t _{PHL}	Propagation delay time, high- to low-level output	See Figure 9	--	0.25	1.0	μs
V _{OH}	High-level output voltage after switching	VS = 50 V, IO = 300 mA, See Figure 9	VS-20	--	--	mV

Parameter Measurement Information

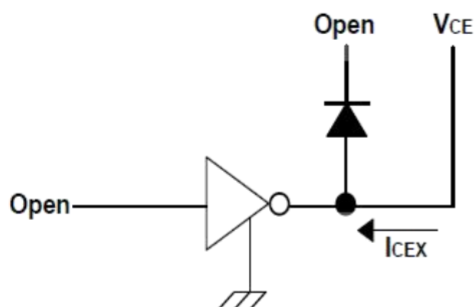


Fig.1 ICEX Test Circuit

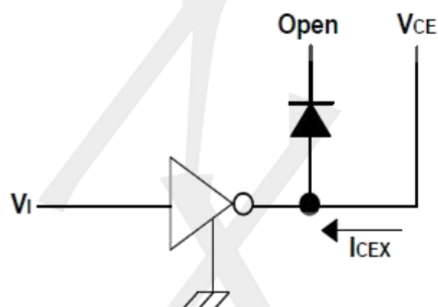


Fig.2 ICEX Test Circuit

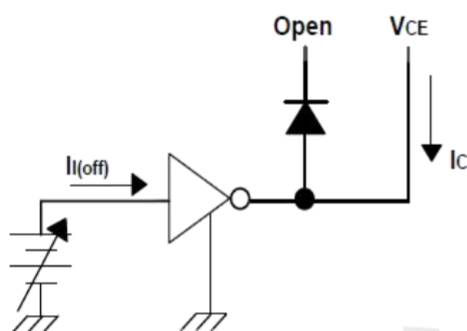


Fig.3 $I_{i(off)}$ Test Circuit

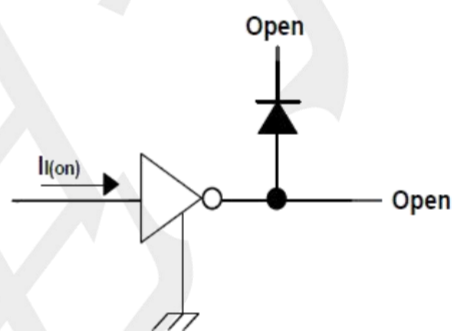


Fig.4 I_i Test Circuit

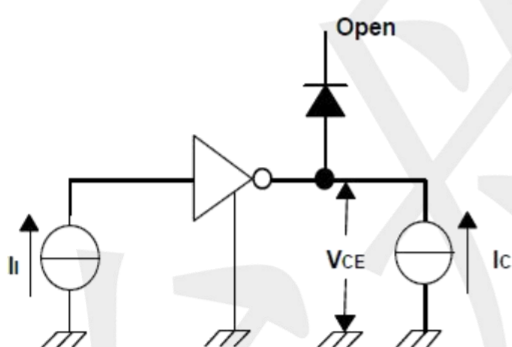


Fig. 5 h_{FE} , $V_{CE(sat)}$ Test Circuit

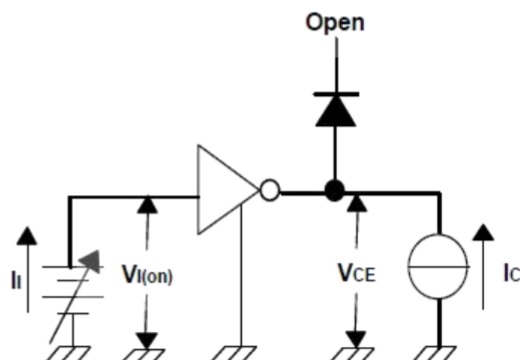


Fig. 6 $V_{i(on)}$ Test Circuit

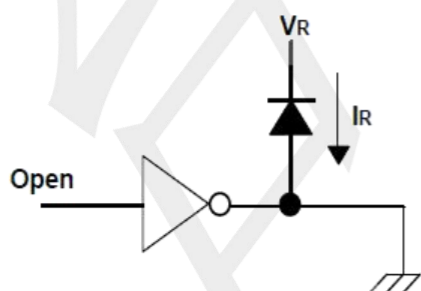


Fig. 7 I_R Test Circuit

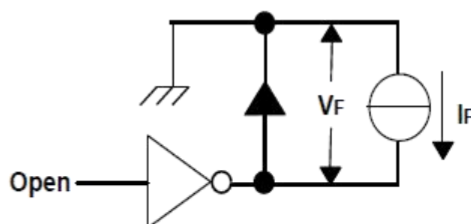


Fig. 8 V_F Test Circuit

Parameter Measurement Information

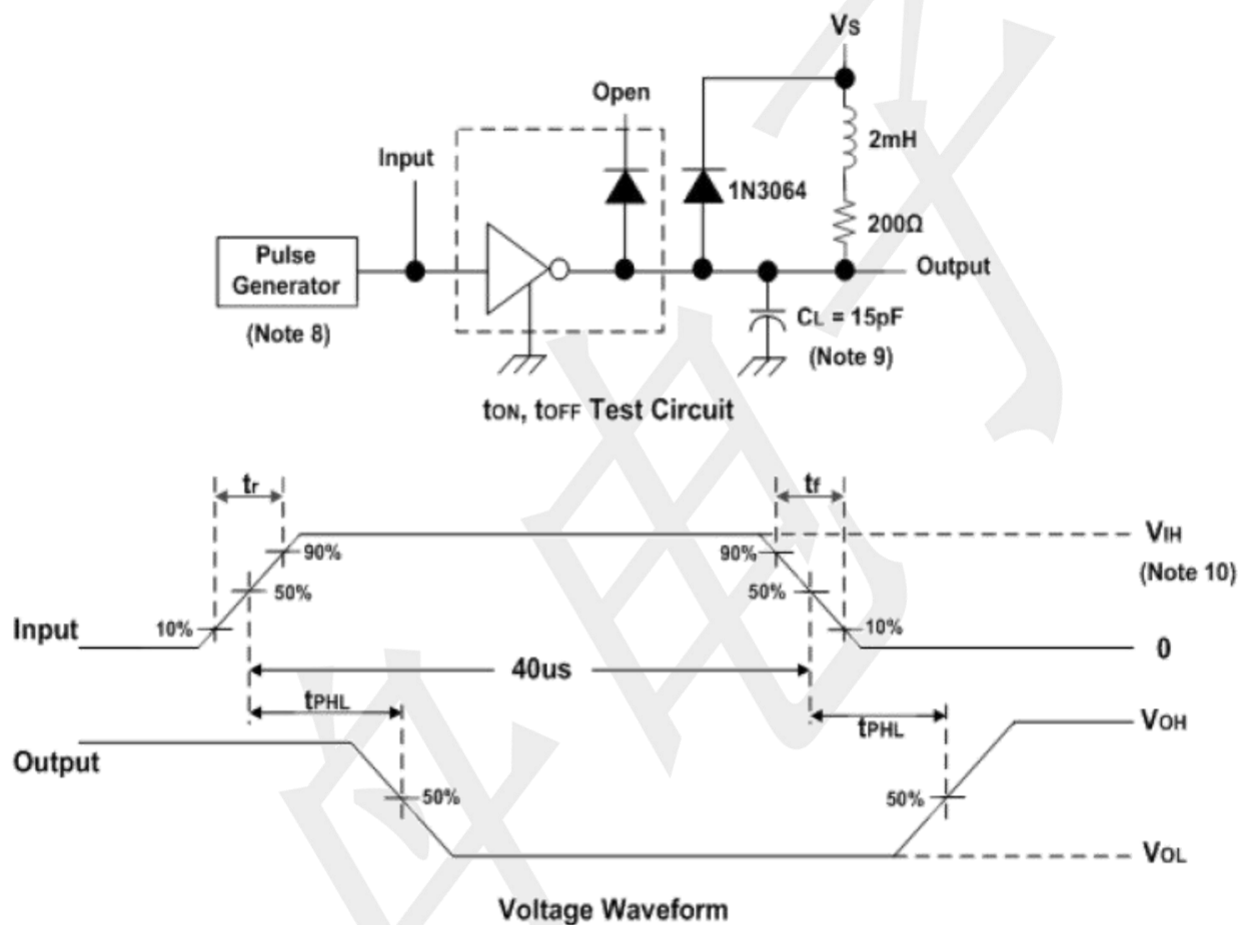


Fig. 9 Latch-Up Test Circuit and Voltage Waveform

Notes: 8. The pulse generator has the following characteristics:

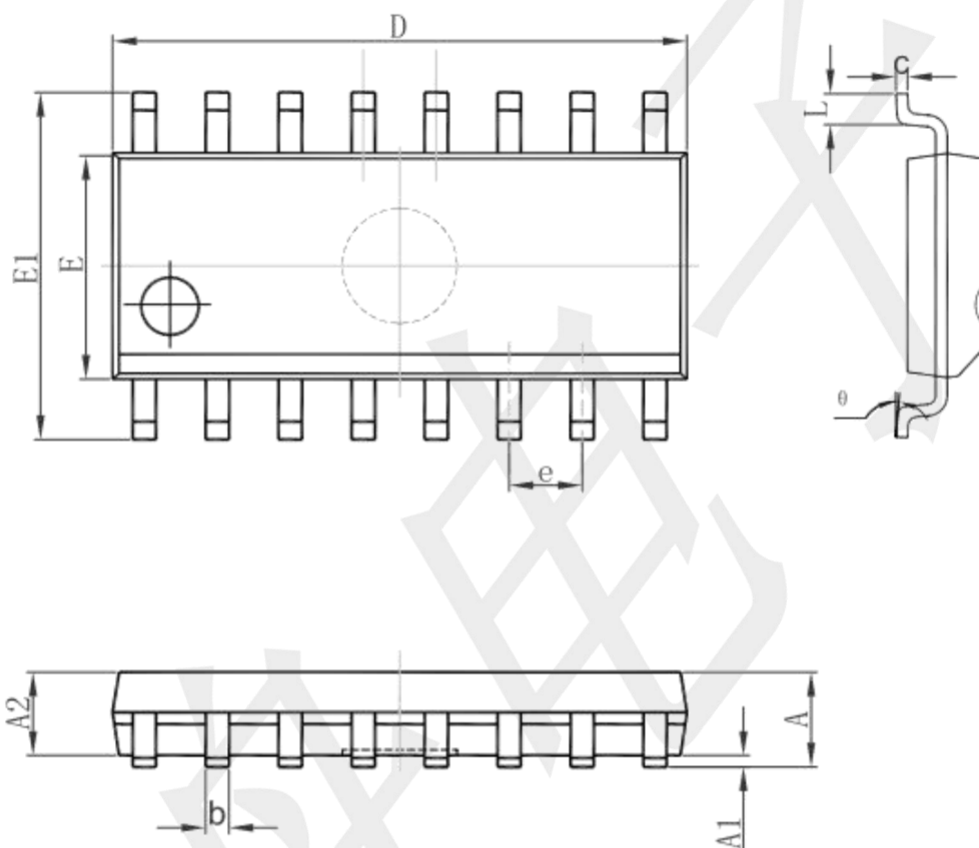
Pulse Width=12.5Hz, output impedance 50Ω, $t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$.

9. C_L includes probe and jig capacitance.

10. $V_{IH} = 3\text{V}$

Package informantion

SOP16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°